Document Number: MC33997

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# Switching Power Supply with Linear Regulators

The 33997 is a medium-power, multi-output power supply integrated circuit that is capable of operating over a wide input voltage range, from 6.0 V up to 26.5 V with 40 V transient capability. It incorporates a sensorless current mode control step-down switching controller regulating directly to 5.0 V. The 3.3 V linear regulator uses an external pass transistor to reduce the 33997 power dissipation. The 33997 also provides a 3.3 V linear standby regulator and two 5.0 V sensor supply outputs protected by internal low-resistance LDMOS transistors.

There are two separate enable pins for the main and sensor supply outputs and standard supervisory functions such as resets with powerup reset delay.

The 33997 provides proper power supply sequencing for advanced microprocessor architectures such as the Freescale MPC5xx and 683xx microprocessor families.

#### **Features**

- Operating Voltage Range 6.0 V up to 26.5 V (40 V transient)
- Step-Down Switching Regulator Output V<sub>DDH</sub> = 5.0 V @ 1400 mA (total)
- Linear Regulator with External Pass Transistor V<sub>DDL</sub> = 3.3 V @ 400 mA
- Low-Power Standby Linear Regulator V<sub>KAM</sub> = 3.3 V @ 10 mA
- Two 5.0 V @ 200 mA (typical) Sensor Supplies V<sub>REF</sub> Protected Against Short-to-Battery and Short-to-Ground with Retry Capability
- Undervoltage Shutdown on the V<sub>DDL</sub>, V<sub>DDH</sub> Outputs with Retry Capability
- Reset Signals
- Power-Up Delay
- Enable Pins for Main Supplies (EN) and Sensor Supplies (SNSEN)
- Power Sequencing for Advanced Microprocessor Architectures
- Pb-Free Packaging Designated by Suffix Code EG

## 33997

#### SWITCHING REGULATOR



DW SUFFIX EG SUFFIX (PB-FREE) 98ASB42344B 24-PIN SOICW

ORDERING INFORMATION					
Device Temperature Range (T <sub>A</sub> ) Package					
MC33997DW/R2	-40°C to 125°C	24 SOICW			
MC33997EG/R2	-40 C to 125 C	24 301000			

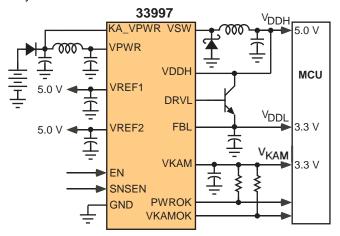
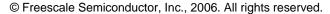


Figure 1. 33997 Simplified Application Diagram

<sup>\*</sup> This document contains certain information on a new product.

Specifications and information herein are subject to change without notice.







#### INTERNAL BLOCK DIAGRAM

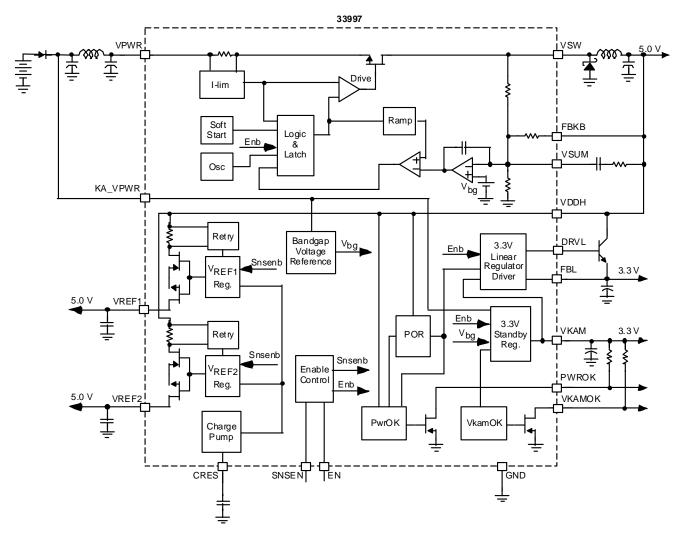


Figure 2. 33997 Simplified Internal Block Diagram



#### **PIN CONNECTIONS**

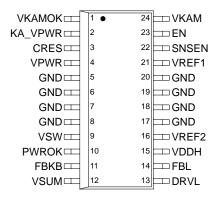


Figure 3. 33997 Pin Connections

Table 1. 33997 Pin Function Definition

Pin Number	Pin Name	Definition
1	VKAMOK	Keep-Alive Output Monitoring. This pin is an "open-drain" output that will be used with a discrete pull-up resistor to VKAM. When the supply voltage to the 33997 is disconnected or lost, the VKAMOK signal goes low.
2	KA_VPRW	Keep Alive Power Supply Pin. This supply pin is used in modules that have both direct battery connections and ignition switch activated connections.
3	CRES	Reservoir Capacitor. This pin is tied to an external "reservoir capacitor" for the internal charge pump.
4	VPWR	Power Supply Pin. Main power input to the IC. This pin is directly connected to the switching regulator power MOSFET. In automotive applications this pin must be protected against reverse battery conditions by an external diode.
5-8	GND	Ground of the integrated circuit.
9	VSW	Internal P-Channel Power MOSFET Drain. VSW is the "switching node" of the voltage buck converter. This pin is connected to the VPWR pin by an integrated p-channel MOSFET.
10	PWROK	Power OK Reset Pin. This pin is an "open-drain" output that will be used with a discrete pull-up resistor to V <sub>KAM</sub> , V <sub>DDH</sub> , or V <sub>DDL</sub> . When either V <sub>DDH</sub> or V <sub>DDL</sub> output voltage goes out of the regulation limits this pin is pulled down.
11	FBKB	Step-Down Switching Regulator Feedback Pin. The FBKB pin is the V <sub>DDH</sub> feedback signal for the switching regulator.
12	VSUM	Error Amplifier "Summing Node". The VSUM pin is connected to the inverting input of the error amplifier. This node is also the "common" point of the integrated feedback resistor divider.
13	DRVL	Drive for V <sub>DDL</sub> (3.3 V) Regulator. The DRVL pin drives the base of an external NPN pass transistor for the V <sub>DDL</sub> linear post regulator. The collector of the VDDL pass transistor is connected to V <sub>DDH</sub> . An example of a suitable pass transistor is BCP68.
14	FBL	Feedback for $V_{DDL}$ (3.3 V) Regulator. The FBL pin is the voltage feedback sense signal from the $V_{DDL}$ (3.3 V) linear post regulator.
15	VDDH	VDDH is an input supply pin providing power for the buffered sensor supplies and the drive circuitry for the 3.3 V linear power regulator. The VDDH pin is supplied from the switching regulator output, capable of providing 5.0 V @ 1400 mA total output current.
16	VFREF2	Sensor Supply #2 Output. The VFREF2 pin is sensor supply output #2.
17-20	GND	Ground of the integrated circuit.
21	VREF1	Sensor Supply #1 Output. The VREF1 pin is sensor supply output #1.
22	SNSEN	Sensor Supply Enable Input. The SNSEN pin is an input, which enables the $V_{REF1}$ and $V_{REF2}$ supplies. It allows the control module hardware/software to shut down the sensor supplies.



## Table 1. 33997 Pin Function Definition (continued)

Pin Number	Pin Name	Definition
23	EN	Enable Input. The EN pin is an input, which enables the main switching regulator and all other functions. When this pin is low, the power supply is in a low quiescent state.
24	VKAM	Keep-Alive (standby) 3.3 V Regulator Output. This is a 3.3 V low quiescent, low dropout regulator for Keep Alive memory.



#### **ELECTRICAL CHARACTERISTICS**

#### **MAXIMUM RATINGS**

#### Table 2. Maximum Ratings

All voltages are with respect to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

Ratings	Symbol	Value	Unit
Main Supply Voltage	V <sub>PWR</sub>	-0.3 to 45	V
Keep-Alive Supply Voltage	KA_V <sub>PWR</sub>	-0.3 to 45	V
Switching Node	V <sub>SW</sub>	-0.5 to 45	V
5.0 V Input Power	V <sub>DDH</sub>	-0.3 to 6.0	V
Sensor Supply	V <sub>REF1</sub>	-0.3 to 18	V
	V <sub>REF2</sub>	-0.3 to 18	
Keep-Alive Supply Voltage	$V_{KAM}$	-0.3 to 6.0	V
Maximum Voltage at Logic I/O Pins	EN	-0.3 to 6.0	V
	SNSEN	-0.3 to 6.0	
	PWROK	-0.3 to 6.0	
	VKAMOK	-0.3 to 6.0	
Charge Pump Reservoir Capacitor Voltage	C <sub>RES</sub>	-0.3 to 18	V
Error Amplifier Summing Node	V <sub>SUM</sub>	-0.3 to 6.0	V
Switching Regulator Output Feedback	FBKB	-0.3 to 6.0	V
VDDL Base Drive	DRVL	-0.3 to 6.0	V
VDDL Feedback	FBL	-0.3 to 6.0	V
ESD Voltage			V
Human Body Model (all pins) (1)	V <sub>ESD1</sub>	±500	
Machine Model (all pins) (1)	V <sub>ESD2</sub>	±100	
Power Dissipation (T <sub>A</sub> = 25°C) (2)	P <sub>D</sub>	800	mW
Thermal Resistance, Junction to Ambient <sup>(3)</sup> , <sup>(4)</sup>	$R_{ heta JA}$	60	°C/W
Thermal Resistance, Junction to Board <sup>(5)</sup>	$R_{ heta JB}$	20	°C/W

- 1. ESD1 testing is performed in accordance with the Human Body Model ( $C_{ZAP}$ =100 pF,  $R_{ZAP}$ =1500  $\Omega$ ). ESD2 testing is performed in accordance with the Machine Model ( $C_{ZAP}$ =200 pF,  $R_{ZAP}$ =0  $\Omega$ )
- 2. Maximum power dissipation at indicated junction temperature.
- 3. Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- 4. Per SEMI G38-87 and JEDEC JESD51-2 with the single layer board horizontal.
- 5. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.



#### Table 2. Maximum Ratings (continued)

All voltages are with respect to ground unless otherwise noted. Exceeding these ratings may cause a malfunction or permanent damage to the device.

Ratings	Symbol	Value	Unit
Operational Package Temperature [Ambient Temperature] (6)	T <sub>A</sub>	-40 to 125	°C
Operational Junction Temperature	TJ	-40 to 150	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	°C
Lead Soldering Temperature (7)	T <sub>S</sub>	260	°C

- 6. The limiting factor is junction temperature, taking into account the power dissipation, thermal resistance, and heat sinking.
- 7. Lead soldering temperature limit is for 10 seconds maximum duration. Not designed for immersion soldering. Exceeding these limits may cause malfunction or permanent damage to the device.



#### STATIC ELECTRICAL CHARACTERISTICS

#### **Table 3. Static Electrical Characteristics**

Characteristics noted under conditions 9.0 V  $\leq$  V<sub>PWR</sub>  $\leq$  16 V, -40°C  $\leq$  T<sub>J</sub> = T<sub>A</sub>  $\leq$  125°C, using the typical application circuit (see <u>Figure</u>) unless otherwise noted. Typical values noted reflect the approximate parameter mean at T<sub>A</sub> = 25°C under nominal conditions unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
GENERAL	1		L	L	I
Supply Voltage Range					V
Normal Operating Voltage Range (8)	$V_{PWR(N)}$	6.0	_	18	
Extended Operating Voltage Range (8)	$V_{PWR(E)}$	18	_	26.5	
Maximum Transient Voltage - Load Dump (9)	V <sub>PWR(LD)</sub>	_	-	40	V
VPWR Supply Current	I <sub>VPWR</sub>				mA
$EN = 5.0 \text{ V}, V_{PWR} = 14 \text{ V}, \text{No Loads}$		25	-	150	
VPWR Quiescent Supply Current	I <sub>Q_VPWR</sub>				μА
$EN = 0 \text{ V}, \text{ V}_{PWR} = 12 \text{ V}$		5.0	-	15	
KA_VPWR Supply Current,	I <sub>KAVPWR</sub>				mA
$EN = 5.0 \text{ V}$ , $KA_V_{PWR} = 14 \text{ V}$ , No Load on $V_{KAM}$		0.5	_	3.0	
KA_VPWR Quiescent Supply Current	I <sub>Q_KAVPWR</sub>				μА
$EN = 0 V$ , $KA_V_{PWR} = 12 V$		50	_	350	
BUCK REGULATOR (VDDH)					
Buck Converter Output Voltage	V <sub>DDH</sub>				V
$I_{VDDH}$ = 200 mA to 1.4 A, $V_{PWR}$ = KA_ $V_{PWR}$ = 14 V		4.9	_	5.1	
Buck Converter Output Voltage	$V_{DDH}$				V
$I_{VDDH} = 1.4 \text{ A}, V_{PWR} = KA_{VPWR} = 6.0 \text{ V}$		4.9	_	5.1	
VDDH Line Regulation	REGLN <sub>VDDH</sub>				mV
$V_{PWR} = KA_V_{PWR} = 10 \text{ V}$ to 14 V, $I_{VDDH} = 200 \text{ mA}$		-20	_	30	
VDDH Load Regulation					mV
$V_{PWR}$ = KA_ $V_{PWR}$ = 14 V, $I_{VDDH}$ = 200 mA to 1.4 A	REGLD <sub>VDDH</sub>	-20	-	20	
$V_{PWR}$ = KA_ $V_{PWR}$ = 6.0 V, $I_{VDDH}$ = 200 mA to 1.4 A		-20	_	20	
VDDH Active Discharge Resistance	R <sub>HDISCH</sub>				Ω
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, EN = 0 \text{ V}, I_{VDDH} = 10 \text{ mA}$		1.0	_	15	
P-CHANNEL MOSFET					
Drain-Source Breakdown Voltage—Not Tested (10)	BV <sub>DSS</sub>	45	-	-	V
Drain-Source Current Limit—Not Tested (10)	ISC <sub>SW1</sub>	_	-7.0	-	Α

- 8. V<sub>DDH</sub> is fully functional when the 33997 is operating at higher battery voltages, but these parameters are not tested. The test condition as are:
  - a)  $V_{DDH}$  must be between 4.9 V and 5.1 V (200 mA to 1.4 A) for  $V_{PWR}$  = 14 V to 18 V.
  - b)  $V_{DDH}$  must be between 4.8 V and 5.5 V (200 mA to 1.4 A) for  $V_{PWR}$  = 18 V to 26.5 V.
- 9. Part can survive, but no parameters are guaranteed.
- 10. Guaranteed by design but not production tested.



#### Table 3. Static Electrical Characteristics (continued)

Characteristics noted under conditions 9.0 V  $\leq$  V<sub>PWR</sub>  $\leq$  16 V, -40°C  $\leq$  T<sub>J</sub> = T<sub>A</sub>  $\leq$  125°C, using the typical application circuit (see <u>Figure</u>) unless otherwise noted. Typical values noted reflect the approximate parameter mean at T<sub>A</sub> = 25°C under nominal conditions unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
LINEAR REGULATOR (VDDL)	<u>'</u>		•	•	•
VDDL Output Voltage	$V_{\mathrm{DDL}}$				V
$VPWR = KA_VPWR = 14 V$ , $I_{VDDL} = 200 mA$		3.15	_	3.45	
VDDL Line Regulation	REGLN <sub>VDDL</sub>				mV
$V_{DDH}$ = 4.8 V to 5.2 V, $I_{VDDL}$ = 400 mA		-70	-	70	
VDDL Load Regulation	REGLD <sub>VDDL</sub>				mV
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, I_{VDDL} = 10 \text{ mA to } 400 \text{ mA}$		-70	-	70	
DRVL Output Current	I <sub>DRVL</sub>				mA
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, VDRVL = 1.0 \text{ V}$		5.0	11	25	
VDDL Active Discharge Resistance	R <sub>LDISCH</sub>				Ω
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, EN = 0 \text{ V}, I_{FBL} = 10 \text{ mA}$		1.0	-	10	
VDDH to VDDL Active Clamp Resistance	R <sub>CLAMP</sub>				Ω
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, EN = 0 \text{ V}, I_{VDDH} = 50 \text{ mA}, V_{FBKB} = 0 \text{ V}$		0.6	-	10	
VDDL Output Capacitor Capacitance (11)	C <sub>VDDL</sub>	-	68	-	μF
VDDL Output Capacitor ESR (11)	ESR <sub>VDDL</sub>	_	0.125	_	Ω
KEEP-ALIVE (STANDBY) REGULATOR (VKAM)					JI.
VKAM Output Voltage	$V_{KAM}$				V
$I_{VKAM} = 5.0 \text{ mA}, \text{ VPWR} = KA\_V_{PWR} = 18 \text{ V}, \text{ EN} = 5.0 \text{ V}$		3.0	-	3.6	
VKAM Output Voltage, EN = 0 V (Standby Mode)	V <sub>KAM</sub>				V
$V_{PWR} = KA_V_{PWR} = 26 \text{ V}, I_{VKAM} = 0.5 \text{ mA}$		3.0	-	3.6	
$V_{PWR} = KA_V_{PWR} = 18 \text{ V}, I_{VKAM} = 5.0 \text{ mA}$		3.0	-	3.6	
$V_{PWR} = KA_V_{PWR} = 5.0 \text{ V}, I_{VKAM} = 10.0 \text{ mA}$		3.0	-	3.6	
$V_{PWR} = 0 \text{ V, KA\_V}_{PWR} = 3.5 \text{ V, } I_{VKAM} = 5.0 \text{ mA}$		2.0	-	3.5	
VKAM Line Regulation, EN = 0 V (Standby Mode)	$REGgLN_VKAM$				mV
$V_{PWR} = KA_V_{PWR} = 5.0 \text{ V to } 18 \text{ V}, I_{VKAM} = 2.0 \text{ mA}$		-20	-	20	
VKAM Load Regulation, EN = 0 V (Standby Mode)	REGLD <sub>VKAM</sub>				mV
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, I_{VKAM} = 1.0 \text{ mA} \text{ to } 10 \text{ mA}$		0.0	-	100	
Differential Voltage V <sub>KAM</sub> - V <sub>DDL</sub>	REG <sub>VKAM</sub>				mV
EN = 5.0 V, $I_{VKAM}$ = 5.0 mA, $V_{PWR}$ = KA_ $V_{PWR}$ = 14 V, $I_{VDDL}$ = 200 mA		-20	_	20	
VKAM Output Capacitor Capacitance (11)	C <sub>VKAM</sub>	-	4.7	-	μF
VKAM Output Capacitor ESR (11)	ESR <sub>VKAM</sub>	_	1.4	-	Ω

#### Notes

11. Recommended value.



#### Table 3. Static Electrical Characteristics (continued)

Characteristics noted under conditions 9.0 V  $\leq$  V<sub>PWR</sub>  $\leq$  16 V, -40°C  $\leq$  T<sub>J</sub> = T<sub>A</sub>  $\leq$  125°C, using the typical application circuit (see <u>Figure</u>) unless otherwise noted. Typical values noted reflect the approximate parameter mean at T<sub>A</sub> = 25°C under nominal conditions unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
SENSOR SUPPLIES (VREF1, VREF2)			•	•	
VREF On-Resistance, T <sub>A</sub> = -40°C	R <sub>DS(ON)</sub>				mΩ
$\rm I_{VREF}$ = 200 mA, $\rm I_{VDDH}$ = 200 mA, $\rm V_{PWR}$ = KA_V_{PWR} = 14 V, EN = 5.0 V		_	_	280	
VREF On-Resistance, T <sub>A</sub> = +25°C	R <sub>DS(ON)</sub>				mΩ
$\rm I_{VREF}$ = 200 mA, $\rm I_{VDDH}$ = 200 mA, $\rm V_{PWR}$ = KA_V_{PWR} = 14 V, EN = 5.0 V		_	_	350	
VREF On-Resistance, T <sub>A</sub> = +125°C	R <sub>DS(ON)</sub>				mΩ
$\rm I_{VREF}$ = 200 mA, $\rm I_{VDDH}$ = 200 mA, $\rm V_{PWR}$ = KA_V_{PWR} = 14 V, EN = 5.0 V		_	_	455	
VREF Short-to-Battery Detect Current	I <sub>SC_BAT</sub>				mA
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, EN = 5.0 \text{ V}, SNSEN = 5.0 \text{ V}$		500	_	900	
VREF Short-to-Ground Detect Current	I <sub>SC_GND</sub>				mA
$V_{PWR} = KA_{VPWR} = 14 \text{ V}, EN = 5.0 \text{ V}, SNSEN = 5.0 \text{ V}$		500	_	900	
Maximum Output Capacitance (Total) (12)	$C_{VREF}$	33	_	39	nF
SUPERVISORY CIRCUITS (VPWR)				•	
PWROK Undervoltage Threshold on V <sub>DDL</sub> , FBL Ramps Down	V <sub>FBL(THL)</sub>				V
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, I_{VDDH} = 200 \text{ mA}$		2.6	_	3.1	
PWROK Undervoltage Threshold on V <sub>DDH</sub>	V <sub>DDH(THL)</sub>				V
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, I_{VDDH} = 200 \text{ mA}$		4.5	-	4.8	
VDDH Overvoltage Threshold	V <sub>DDH(THH)</sub>				V
$V_{PWR} = KA_V_{PWR} = 10 \text{ V}, I_{VDDH} = 200 \text{ mA}$	, ,	5.12	_	5.7	
PWROK Open Drain On-Resistance	R <sub>DS(ON)</sub>				Ω
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, EN = 5 \text{ V}, I_{PwrOK} = 5.0 \text{ mA}$		-	_	200	
VKAMOK Threshold,	V <sub>KAM(THL)</sub>				V
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, I_{VDDH} = 200 \text{ mA}$		0.9	_	1.9	
VKAMOK Threshold on V <sub>PWR</sub> , V <sub>PWR</sub> Ramps Up	V <sub>PWRok(TH)</sub>				V
$KA_V_{PWR} = 14 \text{ V}, I_{VDDH} = 200 \text{ mA}$		4.0	_	5.0	
VKAMOK Open Drain On-Resistance	R <sub>DS(ON)</sub>				Ω
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, EN = 0 \text{ V}, I_{VKAMOK} = 10 \text{ mA}$		50	-	200	
Enable Input Voltage Threshold (Pin EN)	V <sub>IH</sub>	1.0	-	2.0	V
Enable Pull-Down Current (Pin EN), EN = 1.0 V V <sub>DDH</sub> to V <sub>IL(min)</sub>	I <sub>PD</sub>	500	-	1200	nA
Sensor Enable Input Voltage Threshold (Pin SNSEN)	V <sub>IH</sub>	1.0	-	2.0	V
Sensor Enable Pull-Down Current (Pin SNSEN)	I <sub>PD</sub>				nA
SNSEN = 1.0 V $V_{DDH}$ to $V_{IL(min)}$		500	_	1200	

Notes

12. Recommended value.



#### Table 3. Static Electrical Characteristics (continued)

Characteristics noted under conditions 9.0 V  $\leq$  V<sub>PWR</sub>  $\leq$  16 V, -40°C  $\leq$  T<sub>J</sub> = T<sub>A</sub>  $\leq$  125°C, using the typical application circuit (see <u>Figure</u>) unless otherwise noted. Typical values noted reflect the approximate parameter mean at T<sub>A</sub> = 25°C under nominal conditions unless otherwise noted.

Characteristic	Symbol	Min	Тур	Max	Unit
CHARGE PUMP (CRES)					
Charge Pump Voltage	V <sub>CRES</sub>				V
$V_{PWR} = KA_V_{PWR} = 14 \text{ V}, I_{VDDH} = 200 \text{ mA}, I_{CP} = 0 \mu\text{A}$		12	_	15	
$V_{PWR}$ = KA_ $V_{PWR}$ = 14 V, $I_{VDDH}$ = 200 mA, $I_{CP}$ = 10 $\mu$ A		12	_	15	



#### **DYNAMIC ELECTRICAL CHARACTERISTICS**

#### **Table 4. Dynamic Electrical Characteristics**

Characteristics noted under conditions  $9.0 \text{ V} \leq \text{V}_{PWR} \leq 16 \text{ V}$ ,  $-40^{\circ}\text{C} \leq \text{T}_{J} = \text{T}_{A} \leq 125^{\circ}\text{C}$  using the typical application circuit (see <u>Figure</u>) unless otherwise noted. Typical values noted reflect the approximate parameter mean at  $\text{T}_{A} = 25^{\circ}\text{C}$  under nominal conditions unless otherwise noted.

			_	I	
Characteristic	Symbol	Min	Тур	Max	Unit
BUCK REGULATOR (VDDH)					
Switching Frequency (13)	f <sub>SW</sub>	_	750	-	kHz
Soft Start Duration (see Figure 4)	t <sub>SS</sub>				ms
$V_{PWR} = KA_V_{PWR} = 6.0 V$		5.0	-	15	
CHARGE PUMP (CRES)					
Charge Pump Current Ramp-Up Time	t <sub>CRES</sub>				ms
$V_{PWR}$ = KA_ $V_{PWR}$ = 14 V, $C_{RES}$ = 22 nF, $V_{CP}$ = 1.0 V to 11 V		1.0	-	20	
Charge Pump Ramp-Up Time	t <sub>CRES</sub>				ms
$V_{PWR}$ = KA_ $V_{PWR}$ = 7.0 V, $C_{RES}$ = 22 nF, $V_{CP}$ = 7.0 V to 10 V		1.0	-	10	
SENSOR SUPPLIES (VREF1, VREF2)					
V <sub>REF</sub> Overcurrent Detection Time (see <u>Figure 7</u> )	t <sub>DET</sub>				μS
$\rm V_{REF}$ Load $\rm R_L = 5.0~\Omega$ to GND, $\rm V_{DDH} = 5.1~V,~V_{PWR} = KA\_V_{PWR} = 10~V,$ EN = 5.0 V, SNSEN = 5.0 V		0.5	_	2.0	
V <sub>REF</sub> Retry Timer Delay (see <u>Figure 7</u> )	t <sub>RET</sub>				ms
$\rm V_{REF}$ Load $\rm R_L=5.0~\Omega$ to GND, $\rm V_{DDH}=5.1~V,~V_{PWR}=KA\_V_{PWR}=10~V,$ EN = 5.0 V, SNSEN = 5.0 V		5.0	_	20	
SUPERVISORY CIRCUITS (VPWR)					
PWROK Delay Time (Power-On Reset) (see Figure 6)	t <sub>D(PWROK)</sub>	5.0	_	15	ms
VKAMOK Delay Time (see Figure 7)	t <sub>D(VKAMOK)</sub>	10	-	30	ms
VDDH Power-Up Delay Time (see Figure 8)	t <sub>D(VPWR)</sub>	1.0	-	10	ms
Fault-Off Timer Delay Time (see Figure 9)	t <sub>FAIL</sub>	1.0	-	10	ms

<sup>13.</sup> Guaranteed by design but not production tested.



#### **TIMING DIAGRAMS**

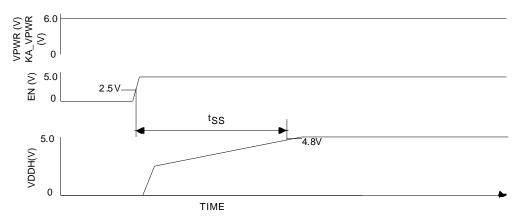


Figure 4. Soft-Start Time

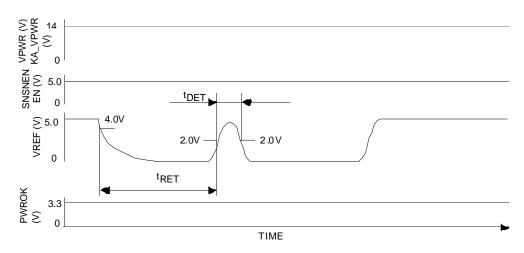


Figure 5. VREF Retry Timer

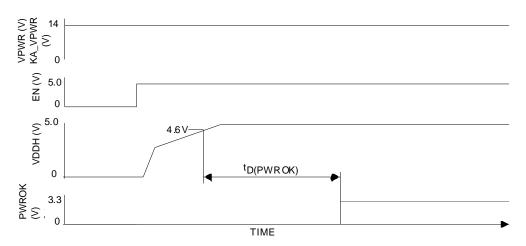


Figure 6. PWROK Delay Timer (Power-On Reset)



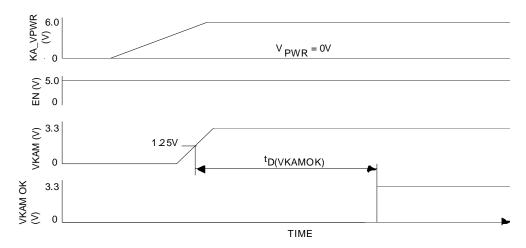


Figure 7. VKAMOK Delay Time

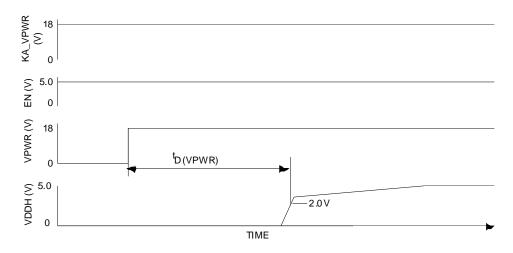


Figure 8. VDDH Power-Up Delay Time

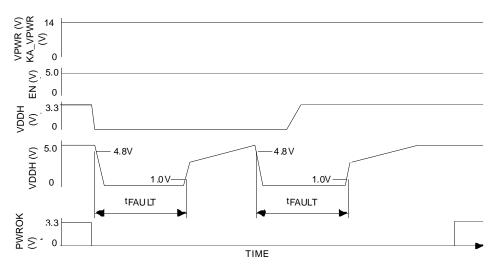


Figure 9. Fault-Off Timer Delay Time



#### **FUNCTIONAL DESCRIPTION**

#### INTRODUCTION

The 33997 multi-output power supply integrated circuit is capable of operating from 6.0 V up to 26.5 V with 40 V transient capability. It incorporates a step-down switching controller regulating directly to 5.0 V. The 3.3 V linear regulator uses an external pass transistor, thus reducing the

power dissipation of the integrated circuit. The 33997 also provides a 3.3 V linear standby regulator and two 5.0 V sensor supply outputs protected by internal low-resistance LDMOS transistors against short-to-battery and short-to-ground.

#### **FUNCTIONAL PIN DESCRIPTION**

#### **SWITCHING REGULATOR (VDDH)**

The switching regulator is a high-frequency (750 kHz), conventional buck converter with integrated high-side p-channel power MOSFET. Its output voltage is regulated to provide 5.0 V with ±2% accuracy and it is intended to directly power the digital and analog circuits of the Electronic Control Module (ECM). The switching regulator output is rated for 1400 mA total output current. This current can be used by the linear regulator VDDL and sensor supplies VREF1 and VREF2. The 33997 switching controller utilizes "Sensorless Current Mode Control" to achieve good line rejection and stabilize the feedback loop. A soft-start feature is incorporated into the 33997. When the device is enabled, the switching regulator output voltage VDDH ramps up to about half of full scale and then takes 16 steps up to the nominal regulation voltage level (5.0 V nominal).

#### 3.3 V LINEAR REGULATOR (VDDL)

The 3.3 V linear post-regulator is powered from the 5.0 V switching regulator output (VDDH). A discrete pass transistor is used to the power path for the VDDL regulator. This arrangement minimizes the power dissipation off the controller IC. The FBL pin is the feedback input of the regulator control loop and the DRVL pin the external NPN pass transistor base drive. Power up, power down, and fault management are coordinated with the 5.0 V switching regulator.

#### **SENSOR SUPPLIES (VREF1) AND (VREF2)**

The sensor supplies are implemented using a protected switch to the main 5.0 V (switching regulator) output. The 33997 integrated circuit provides two low-resistance LDMOS power MOSFETs connected to the switching regulator output (VDDH). These switches have short-to-battery and short-to-ground protection integrated into the IC. When a severe fault conditions is detected, the affected sensor output is turned off and the sensor Retry Timer starts to time out. After the Retry Timer expires, the sensor supply tries to power up again. Sensor supplies VREF can be disabled by pulling the Sensor Enable SNSEN pin low (see Figure 9 for the  $V_{\rm REF}$  Retry Timer operation).

**Notes:** Severe fault conditions on the VREF1 and VREF2 outputs, like hard shorts to either ground or battery, may disrupt the operation of the main regulator V<sub>DDH</sub>. Shorts to

battery above 17 V are considered "double faults" and neither one of the VREF outputs is protected against such conditions.

Depending on the VDDH capacitor value and its ESR value, the severity of the short may disrupt the VDDH operation.

#### **KEEP-ALIVE REGULATOR, STANDBY (VKAM)**

The Keep-Alive Regulator VKAM (keep-alive memory) is intended to provide power for "key off" functions such as nonvolatile SRAM, "KeyOff" timers and controls, KeySwitch monitor circuits, and perhaps a CAN/SCP monitor and wake-up function. It may also power other low-current circuits required during a "KeyOff" condition. The regulated voltage is nominally 3.3 V. A severe fault condition on the VKAM output is signaled by pulling the VKAMOK signal low.

#### KEEP-ALIVE OPERATION STANDBY, POWER-DOWN MODE (VKAM)

When the EN pin is pulled low, the power supply is forced into a low-current standby mode. In order to reduce current drawn by the VPWR and KA\_VPWR pins, all power supply functions are disabled except for the VKAM and Enable (EN) pins. The latter pin is monitored for the "wake-up" signal. The switching transistor gate is actively disabled and the VDDL and VDDH pins are actively pulled low.

#### **POWER-UP DELAY TIMERS**

Two Power-Up Delay timers are integrated into the control section of the integrated circuit. One timer monitors the input voltage at the VPWR input pin (see Figure 5), and the other monitors the input voltage at the KA\_VPWR input pin. In both cases, sufficient supply voltage must be present long enough for the timers to "time out" before the switching regulator can be enabled.

#### **FAULT-OFF TIMER**

If the VDDL output voltage does not reach its valid range at the end of soft-start period, or if the VDDH or VDDL output voltage gets below its PWROK threshold level, the Fault-Off Timer shuts the switching regulator off until the timer "times out" and the switching regulator retries to power up again (see Figure 9 for Fault-Off Timer operation details).



#### **POWER-ON RESET TIMER**

This timer starts to time out at the end of the soft-start period if the VDDH and VDDL outputs are in the valid regulation range. If the timer "times out", then the open-drain PWROK signal is released, indicating that "power is ON".

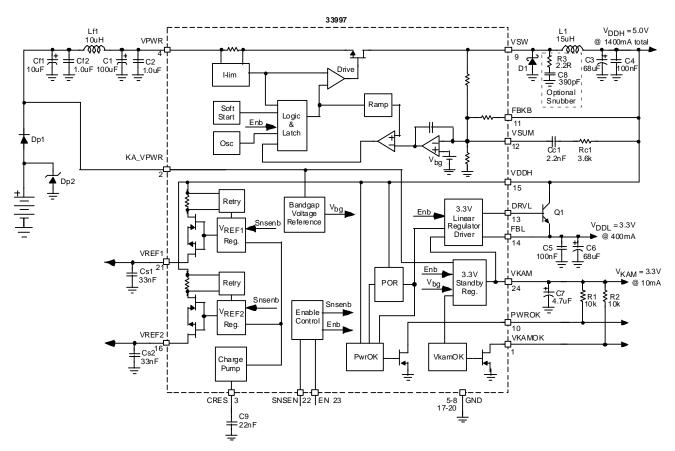
## SUPERVISORY CIRCUITS (PWROK) AND (VKAMOK)

The 33997 has two voltage monitoring open-drain outputs, the PWROK and the VKAMOK pins. PWROK is "active high". This output is pulled low when either of the regulator outputs

(VDDH or VDDL) are below their regulation windows. If both regulator outputs are above their respective lower thresholds, and the Power-On Reset Timer has expired, the output driver is turned off and this pin is at high-impedance state (see Figure 8).

The VKAMOK signal indicates a severe fault condition on the keep-alive regulator output VKAM. The VKAM output voltage is compared to the internal bandgap reference voltage. When the  $V_{KAM}$  falls below the bandgap reference voltage level, the VKAMOK signal is pulled low.

#### TYPICAL APPLICATIONS



Note The VDDH total output current is 1.4 A. This includes the current used by the linear regulator VDDL and buffered outputs VREF1 and VREF2.

Figure 10. 33997 Application Circuit Schematic Diagram

**Table 5. Recommended Components** 

Designator	Value/Rating	Description/Part No.	Manufacturer (15)
Cf1	10 μF/50 V	Aluminum Electrolytic/UUB1H100MNR	Nichicon
Cf2, C2	1.0 μF/50 V	Ceramic X7R/C1812C105K5RACTR	Kemet
C1	100 μF/50 V	Aluminum Electrolytic/UUH1V101MNR	Nichicon
C3 <sup>(14)</sup>	68 μF/10 V	Tantalum/T494D686M010AS	Kemet
C6	68 μF/10 V	Tantalum/T494D686M010AS	Kemet
C7	4.7 μF/10 V	Tantalum/T494A475M010AS	Kemet
C4, C5	100 nF/16 V	Ceramic X7R	Any Manufacturer
C8 (Optional)	390 pF/50 V	Ceramic X7R	Any Manufacturer

- 14. It is possible to use ceramic capacitors in the switcher output, e.g. C3 = 2 x 22 μF/6.3 V X7R ceramic. In this case the compensation resistor has to be changed to Rc1 = 200 Ω to stabilize the switching regulator operation.
- 15. Freescale does not assume liability, endorse, or warrant components from external manufacturers that are referenced in circuit drawings or tables. While Freescale offers component recommendations in this configuration, it is the customer's responsibility to validate their application.



**Table 5. Recommended Components (continued)** 

Designator	Value/Rating	Description/Part No.	Manufacturer (15)
C9	22 nF/25 V	Ceramic X7R	Any Manufacturer
Cs1, Cs2	33 nF/25 V	Ceramic X7R	Any Manufacturer
Cc1	2.2 nF/16 V	Ceramic X7R	Any Manufacturer
R1, R2	10 kΩ	Resistor 0805, 5%	Any Manufacturer
R3 (Optional)	2.2 Ω	Resistor 0805, 5%	Any Manufacturer
Rc1	3.6 kΩ	Resistor 0805, 5%	Any Manufacturer
Lf1	10 μH	CDRH127-100M or SLF10145-100M2R5	Sumida TDK
L1	15 μH	CDRH127-150MC or SLF10145-150M2R2	Sumida TDK
Q1	1.0 A/20 V	Bipolar Transistor/BCP68T1	ON Semiconductor
D1	2.0 A/50 V	Schottky Diode/SS25	General Semiconductor
Dp1	3.0 A/200 V	Diode/MURS320	ON Semiconductor
Dp2	27 V	Transient Voltage Suppressor/SM5A27	General Semiconductor

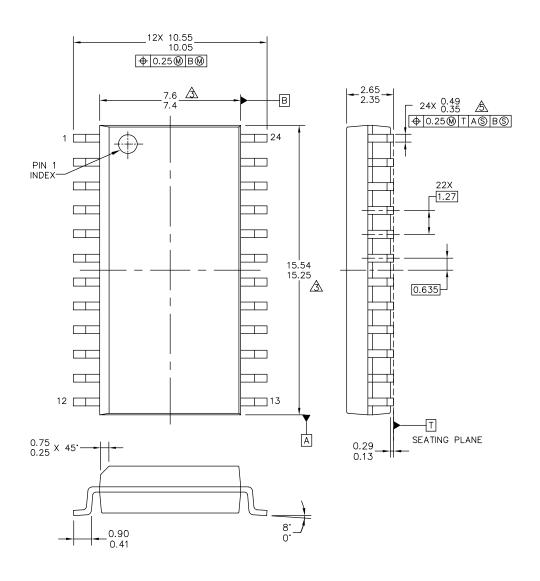
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#### **PACKAGE DIMENSIONS**

For the most current revision of the package, visit <u>www.freescale.com</u> and perform a keyword search using the "98A" drawing number listed below.



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### **REVISION HISTORY**

REVISION	DATE	DESCRIPTION OF CHANGES	
4.0	6/2006	<ul> <li>Converted to Freescale format</li> <li>Update to the prevailing Freescale form and style.</li> </ul>	



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